

Engineering/Process Change Notice

ECN/PCN No.: 4145

For Manufacturer						
Product Description: PLASTIC SMD MEMS OSCILLATOR	Abracon Part Number / Part Series: EMRB62		□ Documentation only□ ECN⋈ EOL	Series □ Part Number		
Affected Revision:	New Revision:	OL	Application:	☐ Safety 図 Non-Safety		
Prior to Change: Active https://abracon.com/datasheets/Ecliptek/EMRB62.pdf						
After Change: EOL						
Cause/Reason for Change: Discontinuation of manufacturing capability.						
	Chan	ge Plan				
Effective Date: 2/7/2022	Additional Remarks: N/A					
Change Declaration: N/A						
Issued Date: 2/7/2022	Issued By:		Issued Department:			
Approval:	Approval:		Approval:			
	For Abrac	on EOL only				
Last Time Buy (if applicable): 5/7/2022		Alternate Part Number / Part Series: none				
Additional Approval:	Additional Approval	:	Additional Approval:			
Customer Approval (If Applicable)						
Qualification Status: $\square \text{ Approved } \square \text{ Not accepted}$ Note: It is considered approved if there is no feedback from the customer 1 month after ECN/PCN is released.						
Customer Part Number:		Customer Project:				
Company Name:	Company Representative:		Representative Signature	:		
Customer Remarks:	1		1			

Form #7020 | Rev. G | Effective: 02/22/2021 |















REGULATORY COMPLIANCE











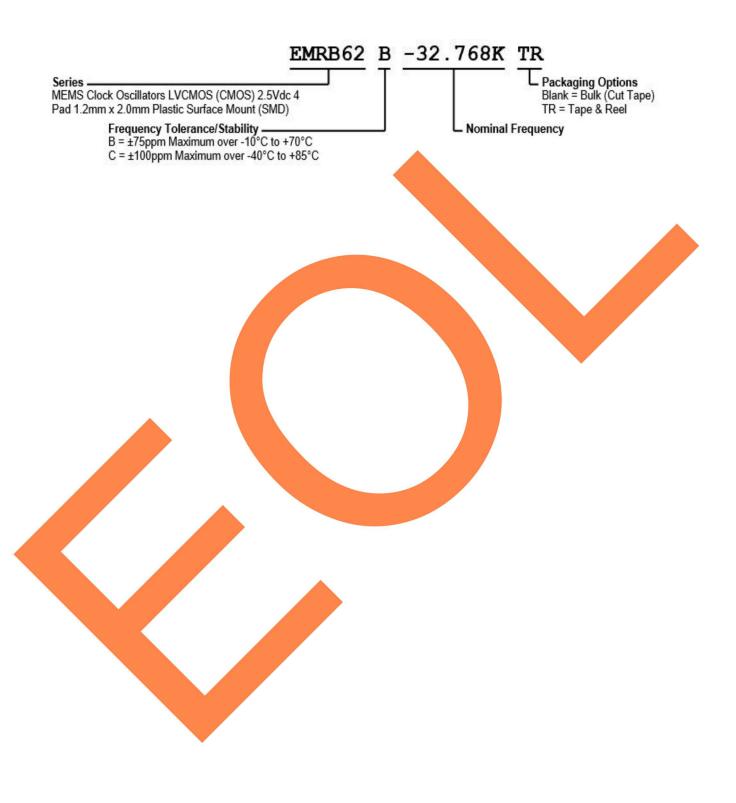
ITEM DESCRIPTION

MEMS Clock Oscillators LVCMOS (CMOS) 2.5Vdc 4 Pad 1.2mm x 2.0mm Plastic Surface Mount (SMD)

ELECTRICAL SPECIFICATIONS		
Nominal Frequency	32.768kHz	
Frequency Tolerance/Stability	Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, and Output Load Change ±75ppm Maximum over -10°C to +70°C ±100ppm Maximum over -40°C to +85°C	
Frequency Tolerance	Measured at 25°C ±2°C, at Vdd=2.5Vdc, Post Reflow ±20ppm Maximum	
Aging at 25°C	±1ppm Maximum First Year	
Supply Voltage	2.5Vdc ±10%	
Input Current	No Load, Nominal Vdd 1.0μA Typical (at 25°C), 2.2μA Maximum at Frequency Tolerance/Stability of ±100ppm Maximum over -40°C to +85°C 1.0μA Typical (at 25°C), 1.9μA Maximum at Frequency Tolerance/Stability of ±75ppm Maximum over -10°C to +70°C	
Output Voltage Logic High (Voh)	IOH = -10µA 90% of Vdd M <mark>inimum</mark>	
Output Voltage Logic Low (Voi)	IOL = +10µA 10% of Vdd <mark>Maximu</mark> m	
Rise/Fall Time	Measured fro <mark>m 10%</mark> to 90% of waveform 100nSec Typi <mark>cal, 200</mark> nSec Maximum	
Duty Cycle	Measured at 5 <mark>0% of wa</mark> veform 50 ±2(%)	
Load Drive Capability	15pF Maximum	
Output Logic Type	CMOS	
Period Jitter (RMS)	Measured at 25°C 35nSec Typical	
Power Supply Ramp	Measured at 0Vdc to 90% of Vdd 100mSec Maximum	
Start Up Time	Measured at Nominal Vdd 180mSec Typical, 500mSec Maximum at Frequency Tolerance/Stability of ±100ppm Maximum over -40°C to +85°C 180mSec Typical, 450mSec Maximum at Frequency Tolerance/Stability of ±75ppm Maximum over -10°C to +70°C	
Storage Temperature Range	-55°C to +125°C	

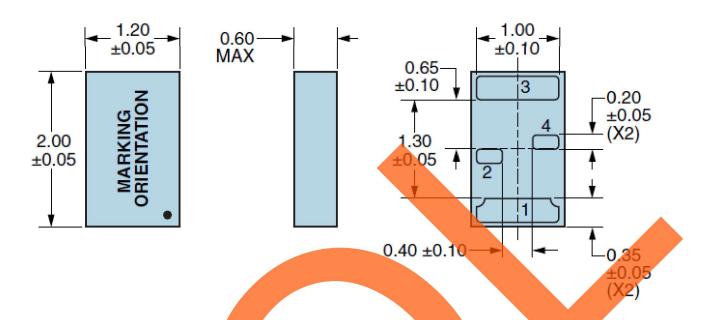


PART NUMBERING GUIDE

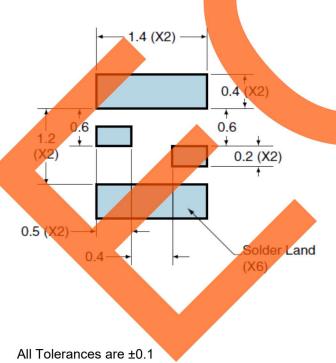




MECHANICAL DIMENSIONS



SUGGESTED SOLDER PAD LAYOUT

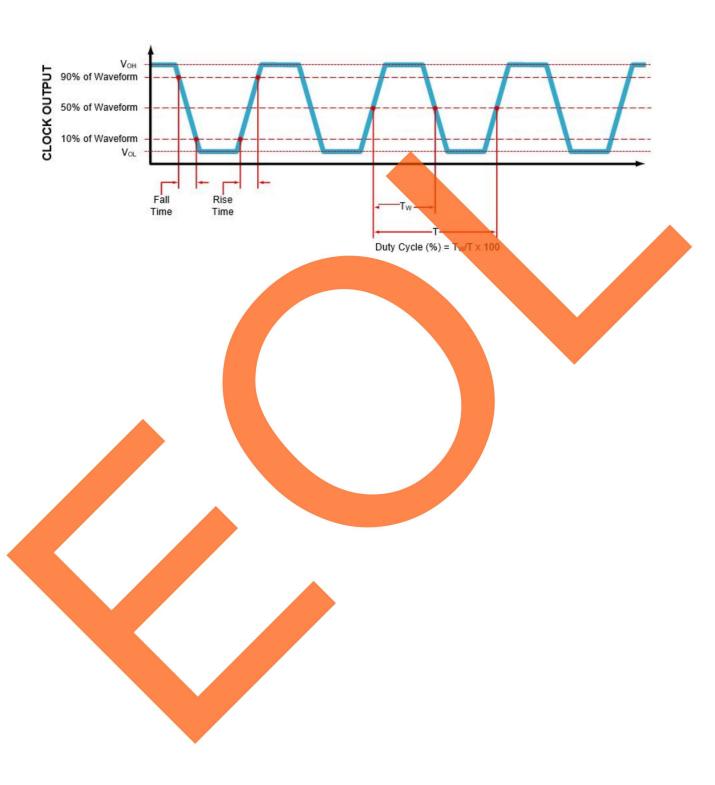


PIN	CONNECTION
1/	No Connect
2	Ground
3	Output
4	Supply Voltage

All Dimensions in Millimeters

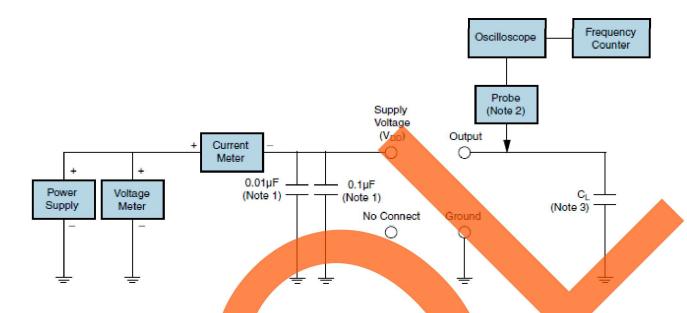


OUTPUT WAVEFORM & TIMING DIAGRAM





TEST CIRCUIT FOR CMOS OUTPUT



- Note 1: An external 0.01µF ceramic bypass capacitor in parallel with a 0.1µF high frequency ceramic bypass capacitor close (less Than 2mm) to the package ground and supply voltage pin is required.

 Note 2: A low input capacitance (<12pF), 10X attentuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz)
- Passive probe is recommended.
- Note 3: Capacitance value CL includes sum of all probe and fixture capacitance. See applicable specification sheet for 'Load Drive Capability'.

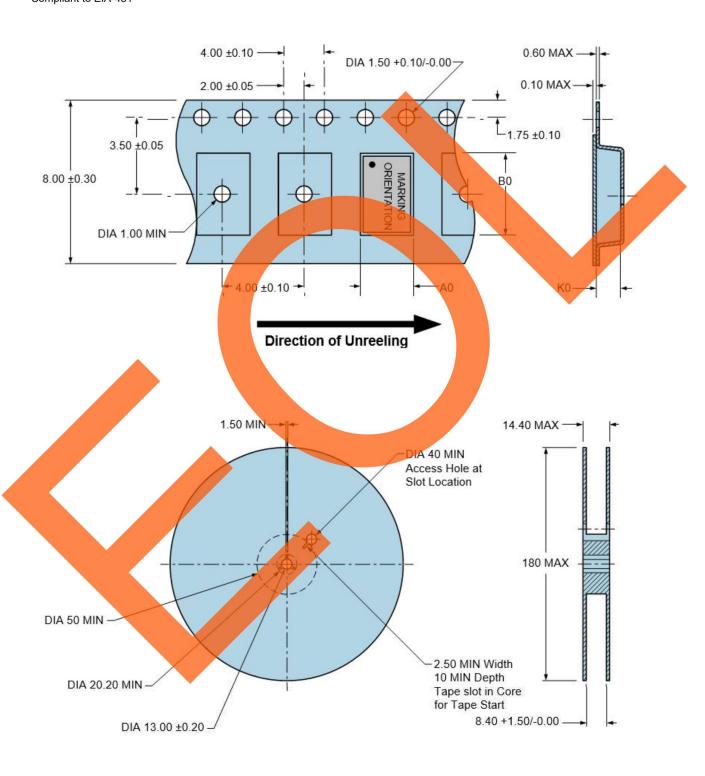


TAPE & REEL DIMENSIONS

Quantity per Reel: 3000 Units

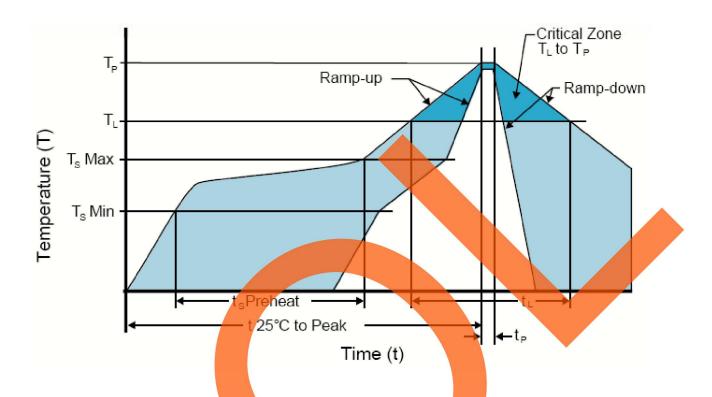
All Dimensions in Millimeters

Compliant to EIA-481





RECOMMENDED SOLDER REFLOW METHOD



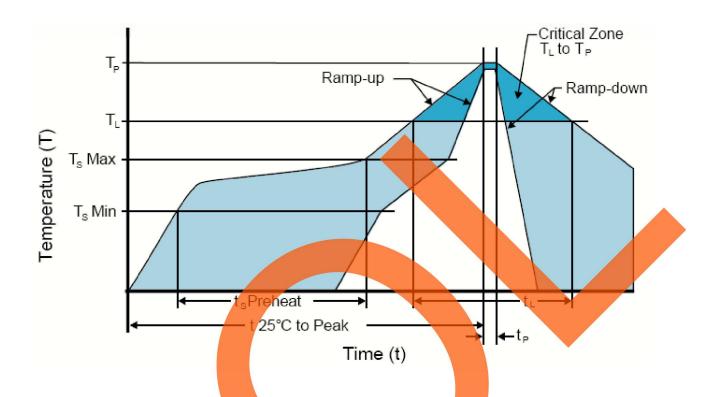
HIGH TEMPERATURE INFRARED/CONVECTION		
T _S MAX to T _L (Ramp-up Rate)	3°C/Second Maximum	
Preheat		
- Temperature Minimum (T _s MIN)	150°C	
- Temperature Typical (T _S TYP)	175°C	
- Temperature Maximum(T _s MAX)	200°C	
- Time (t _s)	60 - 180 Seconds	
Ramp-up Rate (T _L to T _P)	3°C/Second Maximum	
Time Maintained Above:		
- Temperature (T⊥)	217°C	
- Time (t _L)	60 - 150 Seconds	
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum	
Target Peak Temperature(Tp Target)	250°C +0/-5°C	
Time within 5°C of actual peak (t _p)	20 - 40 Seconds	
Ramp-down Rate	6°C/Second Maximum	
Time 25°C to Peak Temperature (t)	8 Minutes Maximum	
Moisture Sensitivity Level	Level 1	
Additional Notes	Temperatures shown are applied to body of device.	

High Temperature Manual Soldering

260°C Maximum for 5 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)



RECOMMENDED SOLDER REFLOW METHOD



LOW TEMPERATURE INFRARED/CONVECTION		
T _s MAX to T _L (Ramp-up Rate)	5°C/Second Maximum	
Preheat		
- Temperature Minimum (T _s MIN)	N/A	
- Temperature Typical (T _s TYP)	150°C	
- Temperature Maximum(T _s MAX)	N/A	
- Time (t _s)	60 - 120 Seconds	
Ramp-up Rate (T _L to T _P)	5°C/Second Maximum	
Time Maintained Above:	<u> </u>	
- Temperature (T⊥)	150°C	
- Time (t _L)	200 Seconds Maximum	
Peak Temperature (T _P)	240°C Maximum	
Target Peak Temperature (Tp Target)	240°C Maximum 2 Times / 230°C Maximum 1 Time	
Time within 5°C of actual peak (tp)	10 Seconds Maximum 2 Times / 80 Seconds Maximum 1 Time	
Ramp-down Rate	5°C/Second Maximum	
Time 25°C to Peak Temperature (t)	N/A	
Moisture Sensitivity Level	Level 1	
Additional Notes	Temperatures shown are applied to body of device.	

Low Temperature Manual Soldering

185°C Maximum for 10 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)